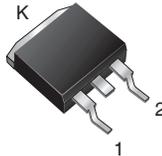
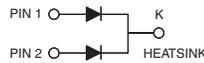


Dual High Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.46 \text{ V}$ at $I_F = 5 \text{ A}$
TMBS®
 TO-263AB

VB40M120C


FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-263AB

 Molding compound meets UL 94 V-0 flammability rating
 Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 20 A
V_{RRM}	120 V
I_{FSM}	250 A
V_F at $I_F = 20 \text{ A}$	0.64 V
$T_J \text{ max.}$	150 °C
Package	TO-263AB
Diode variations	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VB40M120C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	120	V
Maximum average forward rectified current (fig. 1)		per device	40
		per diode	20
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	250	A
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.54	-	V
	$I_F = 10\text{ A}$			0.64	-	
	$I_F = 20\text{ A}$			0.79	0.89	
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.46	-	
	$I_F = 10\text{ A}$			0.54	-	
	$I_F = 20\text{ A}$			0.64	0.72	
Reverse current per diode	$V_R = 90\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	4	-	μA
		$T_A = 125\text{ }^\circ\text{C}$		3	-	mA
	$V_R = 120\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$		-	500	μA
		$T_A = 125\text{ }^\circ\text{C}$		6	32	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: Pulse width $\leq 20\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VB40M120C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	1.8	$^\circ\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB40M120C-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40M120C-E3/8W	1.39	8W	800/reel	Tape and reel

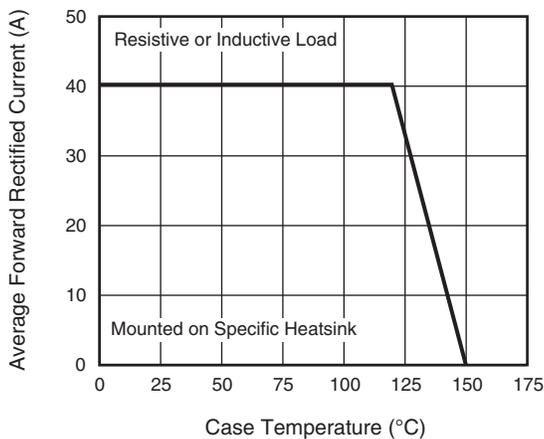
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

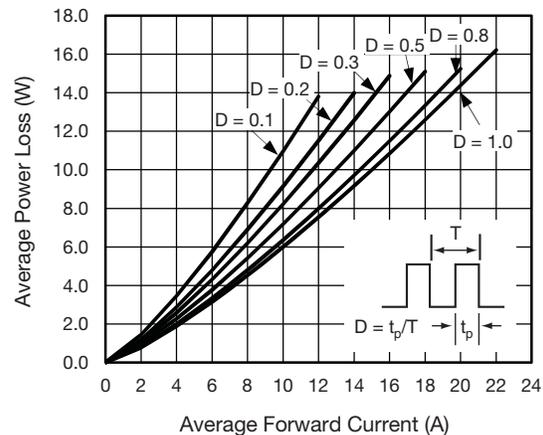


Fig. 2 - Forward Power Loss Characteristics Per Diode

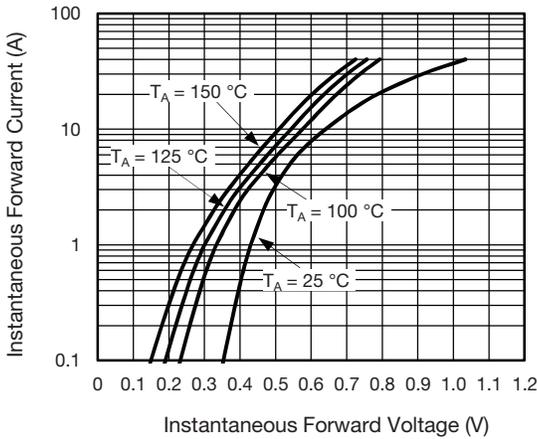


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

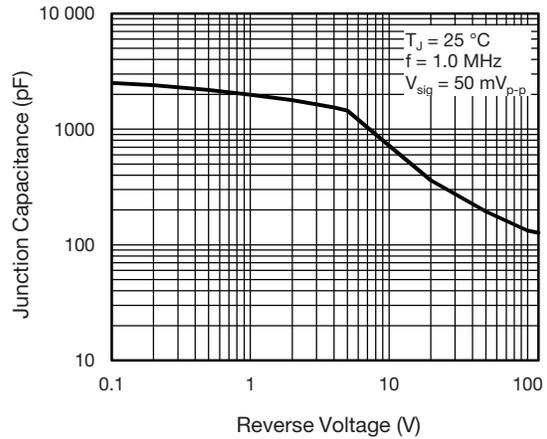


Fig. 5 - Typical Junction Capacitance Per Diode

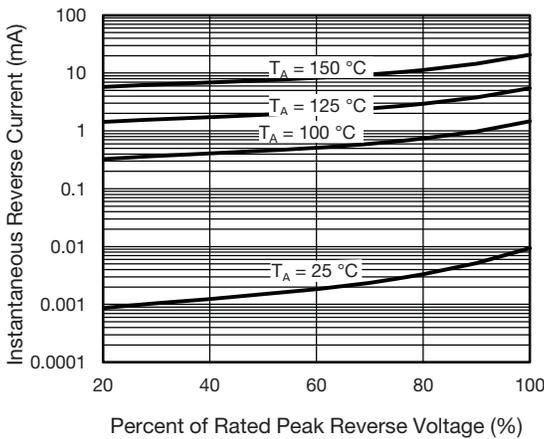


Fig. 4 - Typical Reverse Characteristics Per Diode

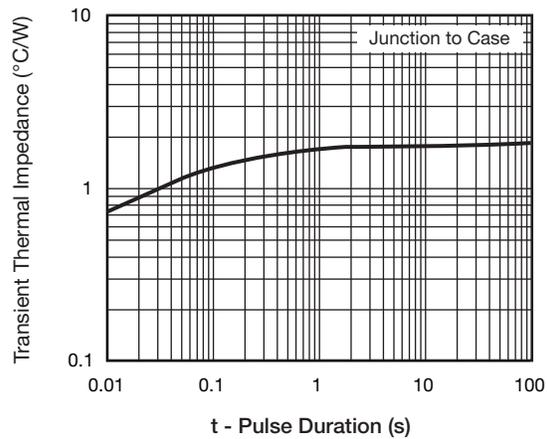
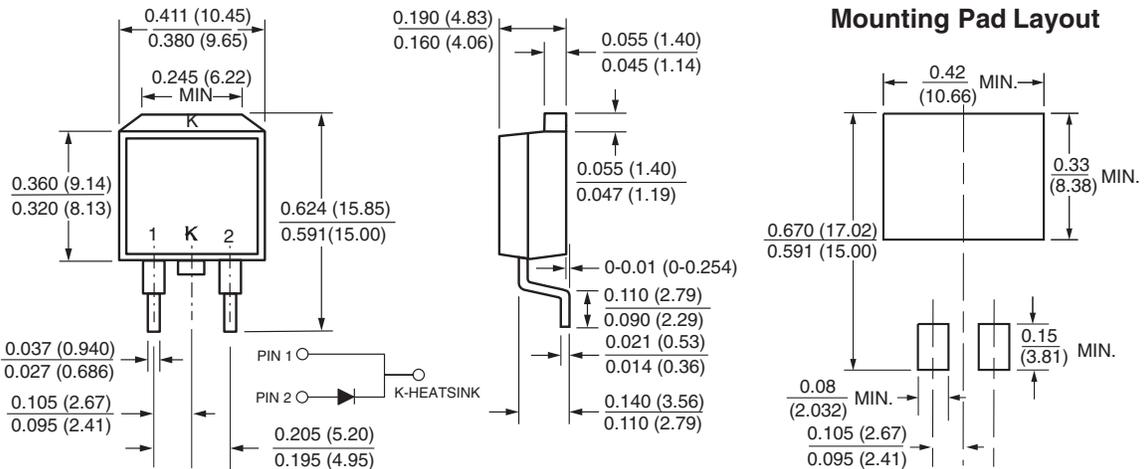


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB





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